RENESAS

EIGHT OUTPUT DIFFERENTIAL BUFFER FOR PCIE GEN1, GEN2 AND QPI ICS9DB823B

General Description

The ICS9DB823B is compatible with the Intel DB800Q Differential Buffer Specification. This buffer provides 8 PCI-Express SRC or 8 QPI clocks. The ICS9DB823B is driven by a differential output pair from a CK410B+ or CK509B main clock generator.

Recommended Application

DB800Q compatible part with PCIe Gen1, Gen 2 and QPI support

Output Features

- 8 0.7V current-mode differential output pairs
- Supports zero delay buffer mode and fanout mode
- Bandwidth programming available
- 50-133 MHz operation in PLL mode
- 33-400 MHz operation in Bypass mode

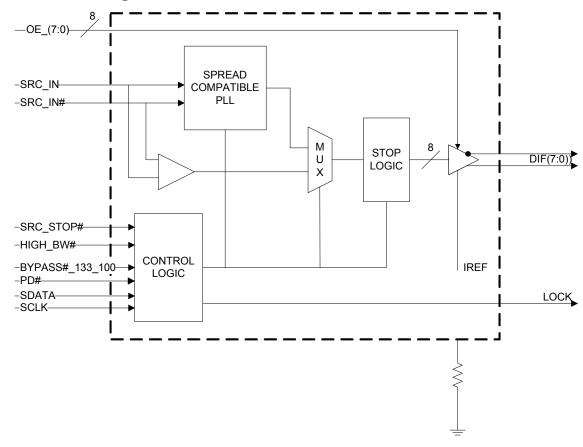
Functional Block Diagram

Features/Benefits

- Spread spectrum modulation tolerant, 0 to -0.5% down spread and +/- 0.25% center spread
- Supports undriven differential outputs in Power Down and DIF_STOP# modes for power management.

Key Specifications

- Outputs cycle-cycle jitter < 50ps
- Output to Output skew <50ps
- Phase jitter: PCIe Gen1 < 86ps peak to peak
- Phase jitter: PCIe Gen2 < 3.0/3.1ps rms
- Phase jitter: QPI < 0.5ps rms

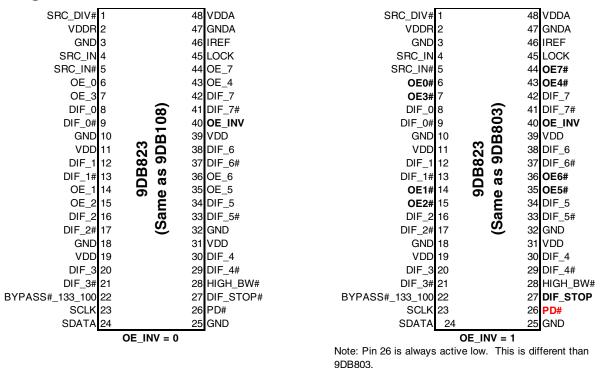


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Note: Polarities shown are for OE_INV=0.

IDT® EIGHT OUTPUT DIFFERENTIAL BUFFER FOR PCIE GEN1, GEN2 AND QPI

Pin Configuration



48-pin SSOP and TSSOP

Power Groups

Pin N	umber	Description
VDD	GND	Description
2	3	SRC_IN/SRC_IN#
11,19,31,39	10,18, 25,32	DIF(7:0)
N/A	47	IREF
48	47	Analog VDD & GND for PLL core

Bypass Readback Table

BYPASS#_133_100	Byte0, bit 3	Byte 0 bit 1
Low	0	0
Mid	1	0
High	0	1

Frequency Selection

BYPASS#_133_100	Voltage	MODE		
Low	<0.8V	Bypass		
Mid	1.2 <vin<1.8v< td=""><td>QPI 133MHz</td></vin<1.8v<>	QPI 133MHz		
High	Vin > 2.0V	PCIe 100MHz		

IDT® EIGHT OUTPUT DIFFERENTIAL BUFFER FOR PCIE GEN1, GEN2 AND QPI

Pin Descriptions for OE_INV=0

PIN #	PIN NAME	PIN TYPE	DESCRIPTION					
1	SRC_DIV#	IN	Active low Input for determining SRC output frequency SRC or SRC/2. 0 = SRC/2, 1= SRC					
2	VDDR	PWR	3V power for differential input clock (receiver). This VDD should be treated as a nanalog power rail and filtered appropriately.					
3	GND	PWR	Ground pin.					
4	SRC_IN	IN	0.7 V Differential SRC TRUE input					
5	SRC_IN#	IN	0.7 V Differential SRC COMPLEMENTARY input					
6	OE_0	IN	Active high input for enabling output 0. 0 =disable outputs, 1= enable outputs					
7	OE_3	IN	Active high input for enabling output 3. 0 =disable outputs, 1= enable outputs					
8	DIF_0	OUT	0.7V differential true clock output					
9	DIF_0#	OUT	0.7V differential Complementary clock output					
10	GND	PWR	Ground pin.					
11	VDD	PWR	Power supply, nominal 3.3V					
12	DIF_1	OUT	0.7V differential true clock output					
13	DIF_1#	OUT	0.7V differential Complementary clock output					
14	OE_1	IN	Active high input for enabling output 1.					
14		IIN	0 =disable outputs, 1= enable outputs					
15	OE_2	IN	Active high input for enabling output 2.					
15	0E_2	IIN	0 =disable outputs, 1= enable outputs					
16	DIF_2	OUT	0.7V differential true clock output					
17	DIF_2#	OUT	0.7V differential Complementary clock output					
18	GND	PWR	Ground pin.					
19	VDD	PWR	Power supply, nominal 3.3V					
20	DIF_3	OUT	0.7V differential true clock output					
21	DIF_3#	OUT	0.7V differential Complementary clock output					
22	BYPASS#_133_100	IN	Input to select Bypass(fan-out), QPI PLL (133MHz) or PCIe PLL (100MHz) mode 0 = Bypass mode, M= QPI, 1= PCIe PLL mode					
23	SCLK	IN	Clock pin of SMBus circuitry, 5V tolerant.					
24	SDATA	I/O	Data pin for SMBus circuitry, 5V tolerant.					

Pin Descriptions for OE_INV=0 (cont.)

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
25	GND	PWR	Ground pin.
26	PD#	IN	Asynchronous active low input pin used to power down the device. The internal clocks are disabled and the VCO and the crystal osc. (if any) are stopped.
27	DIF_STOP#	IN	Active low input to stop differential output clocks.
28	HIGH_BW#	PWR	3.3V input for selecting PLL Band Width 0 = High, 1= Low
29	DIF_4#	OUT	0.7V differential Complementary clock output
30	DIF_4	OUT	0.7V differential true clock output
31	VDD	PWR	Power supply, nominal 3.3V
32	GND	PWR	Ground pin.
33	DIF_5#	OUT	0.7V differential Complementary clock output
34	DIF_5	OUT	0.7V differential true clock output
35		IN	Active high input for enabling output 5.
35	OE_5		0 =disable outputs, 1= enable outputs
36	OE_6	IN	Active high input for enabling output 6. 0 =disable outputs, 1= enable outputs
37	DIF_6#	OUT	0.7V differential Complementary clock output
38	DIF 6		0.7V differential true clock output
39	VDD	PWR	Power supply, nominal 3.3V
40	OE_INV	IN	This latched input selects the polarity of the OE pins. 0 = OE pins active high, 1 = OE pins active low (OE#)
41	DIF_7#	OUT	0.7V differential Complementary clock output
42	DIF_7	OUT	0.7V differential true clock output
			Active high input for enabling output 4.
43	OE_4	IN	0 =disable outputs, 1= enable outputs
44	OE_7	IN	Active high input for enabling output 7. 0 =disable outputs, 1= enable outputs
45	LOCK	OUT	3.3V output indicating PLL Lock Status. This pin goes high when lock is achieved.
46	IREF	IN	This pin establishes the reference for the differential current-mode output pairs. It requires a fixed precision resistor to ground. 475ohm is the standard value for 100ohm differential impedance. Other impedances require different values. See data sheet.
47	GNDA	PWR	Ground pin for the PLL core.
48	VDDA	PWR	3.3V power for the PLL core.

Pin Descriptions for OE_INV=1

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
4			Active low Input for determining SRC output frequency SRC or SRC/2.
1	SRC_DIV#	IN	0 = SRC/2, 1= SRC
2	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as
2	VDDN	ΓVVN	an analog power rail and filtered appropriately.
3	GND	PWR	Ground pin.
4	SRC_IN	IN	0.7 V Differential SRC TRUE input
5	SRC_IN#	IN	0.7 V Differential SRC COMPLEMENTARY input
6	OE0#	IN	Active low input for enabling DIF pair 0.
0			1 =disable outputs, 0 = enable outputs
7	OE3#	IN	Active low input for enabling DIF pair 3.
1	023#		1 =disable outputs, 0 = enable outputs
8	DIF_0	OUT	0.7V differential true clock output
9	DIF_0#	OUT	0.7V differential Complementary clock output
10	GND	PWR	Ground pin.
11	VDD	PWR	Power supply, nominal 3.3V
12	DIF_1	OUT	0.7V differential true clock output
13	DIF_1#	OUT	0.7V differential Complementary clock output
14	OE1#	IN	Active low input for enabling DIF pair 1.
14	011#	IIN	1 =disable outputs, 0 = enable outputs
15	OE2#	IN	Active low input for enabling DIF pair 2.
15	022#		1 =disable outputs, 0 = enable outputs
16	DIF_2	OUT	0.7V differential true clock output
17	DIF_2#	OUT	0.7V differential Complementary clock output
18	GND	PWR	Ground pin.
19	VDD	PWR	Power supply, nominal 3.3V
20	DIF_3	OUT	0.7V differential true clock output
21	DIF_3#	OUT	0.7V differential Complementary clock output
			Input to select Bypass(fan-out), QPI PLL (133MHz) or PCIe PLL (100MHz) mode
22	BYPASS#_133_100	IN	0 = Bypass mode, M = QPI, 1 = PCIe PLL mode
23	SCLK	IN	Clock pin of SMBus circuitry, 5V tolerant.
24	SDATA	I/O	Data pin for SMBus circuitry, 5V tolerant.

ICS9DB823B

Pin Descriptions for OE_INV=1 (cont.)

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
25	GND	PWR	Ground pin.
26	PD#	IN	Asynchronous active low input pin used to power down the device. The internal clocks are disabled and the VCO and the crystal osc. (if any) are stopped.
27	DIF_STOP	IN	Active High input to stop differential output clocks.
28	HIGH_BW#	PWR	3.3V input for selecting PLL Band Width 0 = High, 1= Low
29	DIF_4#	OUT	0.7V differential Complementary clock output
30	DIF_4	OUT	0.7V differential true clock output
31	VDD	PWR	Power supply, nominal 3.3V
32	GND	PWR	Ground pin.
33	DIF_5#	OUT	0.7V differential Complementary clock output
34	DIF_5	OUT	0.7V differential true clock output
35	OE5#	IN	Active low input for enabling DIF pair 5. 1 =disable outputs, 0 = enable outputs
36	OE6#	IN	Active low input for enabling DIF pair 6. 1 =disable outputs, 0 = enable outputs
37	DIF_6#	OUT	0.7V differential Complementary clock output
38	DIF_6	OUT	0.7V differential true clock output
39	VDD	PWR	Power supply, nominal 3.3V
40	OE_INV	IN	This latched input selects the polarity of the OE pins. 0 = OE pins active high, 1 = OE pins active low (OE#)
41	DIF_7#	OUT	0.7V differential Complementary clock output
42	 DIF_7	OUT	0.7V differential true clock output
43	 OE4#	IN	Active low input for enabling DIF pair 4 1 =disable outputs, 0 = enable outputs
44	OE7#	IN	Active low input for enabling DIF pair 7. 1 =disable outputs, 0 = enable outputs
45	LOCK	OUT	3.3V output indicating PLL Lock Status. This pin goes high when lock is achieved.
46	IREF	IN	This pin establishes the reference for the differential current-mode output pairs. It requires a fixed precision resistor to ground. 475ohm is the standard value for 100ohm differential impedance. Other impedances require different values. See data sheet.
47	GNDA	PWR	Ground pin for the PLL core.
48	VDDA	PWR	3.3V power for the PLL core.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the ICS9DB823B. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Symbol	Parameter	Min	Max	Units
VDDA/R	3.3V Core Supply Voltage		4.6	V
VDD	3.3V Logic Supply Voltage		4.6	V
V _{IL}	Input Low Voltage	GND-0.5		V
V _{IH}	Input High Voltage		V _{DD} +0.5V	V
Ts	Storage Temperature	-65	150	°C
Tambient	Ambient Operating Temp	0	70	°C
Tcase	Case Temperature		115	°C
	Input ESD protection			
ESD prot	human body model	2000		V

Electrical Characteristics–Clock Input Parameters

 $T_A = 0 - 70^{\circ}C$; Supply Voltage $V_{DD} = 3.3 \text{ V} + -5\%$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input High Voltage - DIF_IN	VIHDIF	Differential inputs (single-ended measurement)	600	800	1150	mV	1
Input Low Voltage - DIF_IN	VILDIF	Differential inputs (single-ended measurement)		0	300	mV	1
Input Common Mode Voltage	V _{COM}	Common Mode Input Voltage	300		1000	mV	1
Input Amplitude - DIF_IN	V _{SWING}	Peak to Peak value	300		1450	mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA	1
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	J _{DIFIn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

²Slew rate measured through Vswing min centered around differential zero

Electrical Characteristics–Input/Supply/Common Output Parameters

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES	
Input High Voltage	V _{IH}	3.3 V +/-5%	2		V _{DD} + 0.3	V	1	
Input Low Voltage	V _{IL}	3.3 V +/-5%	GND - 0.3		0.8	V	1	
Input High Current	I _{IH}	$V_{IN} = V_{DD}$	-5		5	uA	1	
	I _{IL1}	$V_{IN} = 0 V$; Inputs with no pull-up resistors	-5			uA	1	
Input Low Current	I _{IL2}	$V_{IN} = 0 V$; Inputs with pull-up resistors	-200			uA	1	
Operating Supply Current	I _{DD3.3OP}	Full Active, $C_L = Full load;$			200	mA	1	
Powerdown Current	1	all diff pairs driven			60	mA	1	
Fowerdown Cullent	I _{DD3.3PD}	all differential pairs tri-stated			6	mA	1	
	F _{iPLL}	PCIe Mode (Bypass/133/100= 1)	50	100.00	110	MHz	1	
Input Frequency	F _{iPLL}	QPI Mode (Bypass/133/100= M)	67	133.33	140	MHz	1	
	F _{iBYPASS}	Bypass Mode (Bypass/133/100= 0)	33		400	MHz	1	
Pin Inductance	L _{pin}				7	nH	1	
	C _{IN}	Logic Inputs, except SRC_IN	1.5		5	pF	1	
Capacitance	C _{INSRC_IN}	SRC_IN differential clock inputs	1.5		2.7	pF	1,4	
	C _{OUT}	Output pin capacitance			6	pF	1	
		-3dB point in High BW Mode	2	3 4 MHz	1			
PLL Bandwidth	BW	-3dB point in Low BW Mode	0.7	1	1.4	MHz	1	
PLL Jitter Peaking	t _{JPEAK}	Peak Pass band Gain		1.5	2	dB	1	
Clk Stabilization		From V_{DD} Power-Up and after input clock			1		10	
CIR Stabilization	T _{STAB}	stabilization or de-assertion of PD# to 1st clock			1 ms	1,2		
Input SS Modulation	f _{MODIN}	Allowable Frequency	30	1 ms) 33 kHz	kH7	1		
Frequency	MODIN	(Triangular Modulation)	50			KI IZ	_ '	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion	1		7 nH 5 pF 2.7 pF 6 pF 4 MH 1.4 MH 2 dE 1 ms 33 kH 3 cycl 10 ns 300 us 5 ns 5 ns	3	cvcles	1,3
	"LATOL#	DIF stop after OE# deassertion				-,	.,.	
Tdrive_DIF_Stop#	t _{DRVSTP}	DIF output enable after			10	V uA uA uA uA mA mHz pF pF mHz dB ms kHz cycles ns ws ns v mA ms kHz cycles ns ns <t< td=""><td>1,3</td></t<>	1,3	
-		DIF_Stop# de-assertion DIF output enable after						
Tdrive_PD#	t _{DRVPD}	PD# de-assertion			300	pF pF MHz dB ms kHz cycles ns us ns ns	1,3	
Tfall	t _F	Fall time of PD# and DIF_Stop#			5	ns	1	
Trise	t _R	Rise time of PD# and DIF_Stop#					2	
SMBus Voltage	V _{MAX}	Maximum input voltage			5.5		1	
Low-level Output Voltage	V _{MAX}	@ I _{PULLUP}			0.4	-		
Current sinking at V _{OL}			4		0.4		1	
SCLK/SDATA	I _{PULLUP}	(Max VIL - 0.15) to	4				+	
Clock/Data Rise Time	t _{RSMB}	(Min VIL - 0.15) (0			1000	ns	1	
SCLK/SDATA		(Min VIH + 0.15) to			_		 	
Clock/Data Fall Time	t _{FSMB}	(Max VIL - 0.15)			300	ns	1	
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			100	kHz	1,5	

¹Guaranteed by design and characterization, not 100% tested in production.

²See timing diagrams for timing requirements.

 3 Time from deassertion until outputs are >200 mV

⁴SRC_IN input

⁵The differential input clock must be running for the SMBus to be active

Electrical Characteristics–DIF 0.7V Current Mode Differential Pair

$T_A = 0 - 70^{\circ}C; V_{DD} = 3.3 V$ PARAMETER		$PF, R_S=33\Omega, R_P=49.9\Omega, R_{REF}=475\Omega$	MINI	тур	MAY		NOTES
	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Current Source Output Impedance	Zo ¹		3000			Ω	1
Voltage High	VHigh	Statistical measurement on single ended	660		850	mV	1,2
Voltage Low	VLow	signal using oscilloscope math function. Measurement on single ended signal using absolute value. SS S Variation of crossing over all edges $V_{OL} = 0.175V, V_{OH} = 0.525V$ $V_{OH} = 0.525V V_{OL} = 0.175V$ Measurement from differential wavefrom Bypass Mode, $V_T = 50\%$ PLL Mode $V_T = 50\%$ PLL Mode $V_T = 50\%$ PLL mode Additive Jitter in Bypass Mode PCIe Gen1 phase jitter (Additive in Bypass Mode) PCIe Gen 2 Low Band phase jitter (Additive in Bypass Mode) PCIe Gen 2 High Band phase jitter (Additive in Bypass Mode) PCIe Gen 2 High Band phase jitter (Additive in Bypass Mode) PCIe Gen 2 High Band phase jitter	-150		150		1,2
Max Voltage	Vovs	Measurement on single ended signal			1150	mV	1
Min Voltage	Vuds	using absolute value.	-300			iii v	1
Crossing Voltage (abs)	Vcross(abs)		250		550	mV	1
Crossing Voltage (var)	d-Vcross	Variation of crossing over all edges			140	mV	1
Rise Time	t _r	V _{OL} = 0.175V, V _{OH} = 0.525V	175		700	ps	1
Fall Time	t _f	V _{OH} = 0.525V V _{OL} = 0.175V	175		700	ps	1
Rise Time Variation	d-t _r				125	ps	1
Fall Time Variation	d-t _f				125	ps	1
Duty Cycle	d _{t3}	Measurement from differential wavefrom	45		55	%	1
	t _{pdBYP} Bypass Mode, V _T = 50%	Bypass Mode, $V_T = 50\%$	2500		4500	ps	1
Skew, Input to Output	t _{pdPLL}	PLL Mode V _T = 50%	-250		250	ps	1
Skew, Output to Output	t _{sk3}	V _T = 50%			50	ps	1
Jitter, Cycle to cycle	+	PLL mode			50	ps	1,3
Jiller, Cycle to cycle	t _{jcyc-cyc}	Additive Jitter in Bypass Mode			50	ps	1,3
		(Additive in Bypass Mode)		7	10	ps (pk2pk)	1,4,5
				0	0.1	ps (rms)	1,4,5
	t _{jphaseBYP}	o 1 i		0.7	0.9	ps (rms)	1,4,5
Jitter, Phase		QPI phase jitter (Additive in Bypass Mode)			0.16	ps (rms)	1,5,6
JILLEI, FIIASE		PCIe Gen 1 phase jitter		37	86	ps (pk2pk)	1,4,5
	t	PCIe Gen 2 Low Band phase jitter		1.5	3	ps (rms)	1,4,5
	t _{jphasePLL}	PCIe Gen 2 High Band phase jitter		2.7/ 2.2	3.1	ps (rms)	1,4,5,7
		QPI phase jitter		0.28	0.5	ps (rms)	1,5,6

 $T_A = 0 - 70^{\circ}C; V_{DD} = 3.3 \text{ V} + -5\%; C_L = 2pF, R_S = 33\Omega, R_P = 49.9\Omega, R_{REF} = 475\Omega$

¹Guaranteed by design and characterization, not 100% tested in production.

 2 I_{REF} = V_{DD}/(3xR_R). For R_R = 475 Ω (1%), I_{REF} = 2.32mA. I_{OH} = 6 x I_{REF} and V_{OH} = 0.7V @ Z_O=50 Ω .

3 Measured from differential waveform

⁴ See http://www.pcisig.com for complete specs

⁵ Device driven by 932S421C or equivalent.

6 6.4Gb 12UI

⁷ First number is High Bandwidth Mode, second number is Low Bandwidth Mode

Clock Periods–Differential Outputs with Spread Spectrum Enabled

	urement ndow	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
Sy	mbol	Lg-	-SSC	-ppm error	0ppm	+ ppm error	+SSC	Lg+		
		Absolute Period	Short-term Average	Long-Term Average	Period	Long-Term Average	Short-term Average	Period		
Deti	inition	Minimum	Minimum	Minimum						
		Absolute	Absolute	Absolute	Nominal	Maximum	Maximum	Maximum		
		Period	Period	Period					Units	Notes
	DIF 100	9.949	9.999	10.024	10.025	10.026	10.051	10.101	ns	1,2,3
ne	DIF 133	7.449	7.499	7.518	7.519	7.520	7.538	7.588	ns	1,2,4
Name	DIF 166	5.949	5.999	6.014	6.015	6.016	6.031	6.081	ns	1,2,5
	DIF 200	4.950	5.000	5.012	5.013	5.013	5.026	5.076	ns	1,2,5
Signal	DIF 266	3.700	3.750	3.759	3.759	3.760	3.769	3.819	ns	1,2,5
Si	DIF 333	2.950	3.000	3.007	3.008	3.008	3.015	3.065	ns	1,2,5
	DIF 400	2.450	2.500	2.506	2.506	2.507	2.513	2.563	ns	1,2,5

Clock Periods–Differential Outputs with Spread Spectrum Disabled

Measurement Window		1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
Sy	mbol	Lg-	-SSC	-ppm error	0ppm	+ ppm error	+SSC	Lg+		
Definition		Absolute Period	Short-term Average	Long-Term Average	Period	Long-Term Average	Short-term Average	Period		
Den	Inition	Minimum	Minimum	Minimum						
		Absolute	Absolute	Absolute	Nominal	Maximum	Maximum	Maximum		
		Period	Period	Period					Units	Notes
	DIF 100	9.949		9.999	10.000	10.001		10.051	ns	1,2,3
ne	DIF 133	7.449		7.499	7.500	7.501		7.551	ns	1,2,4
Name	DIF 166	5.949		5.999	6.000	6.001		6.051	ns	1,2,5
al	DIF 200	4.950		5.000	5.000	5.001		5.051	ns	1,2,5
Signal	DIF 266	3.700		3.750	3.750	3.750		3.800	ns	1,2,5
Si	DIF 333	2.950		3.000	3.000	3.000		3.050	ns	1,2,5
	DIF 400	2.450		2,500	2.500	2.500		2.550	ns	1,2,5

¹Guaranteed by design and characterization, not 100% tested in production.

² All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK410B+ accuracy requirements. The 9DB423/823 itself does not contribute to ppm error.

³ Driven by SRC output of main clock, PCIe PLL Mode or Bypass mode

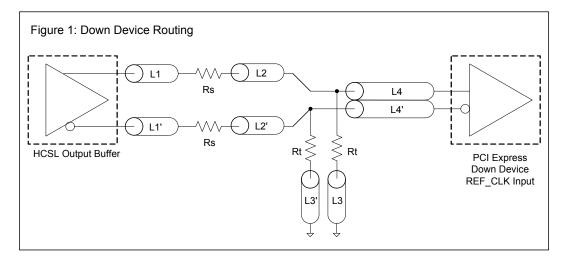
⁴ Driven by CPU output of main clock, QPI PLL Mode or Bypass mode

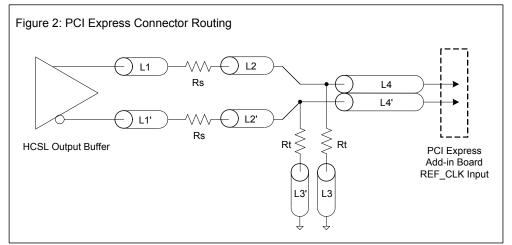
⁵ Driven by CPU output of CK410B+/CK420BQ/CK505 main clock, Bypass mode only

DIF Reference Clock									
Common Recommendations for Differential Routing	Dimension or Value	Unit	Figure						
L1 length, route as non-coupled 50ohm trace	0.5 max	inch	1						
L2 length, route as non-coupled 50ohm trace	0.2 max	inch	1						
L3 length, route as non-coupled 50ohm trace	0.2 max	inch	1						
Rs	33	ohm	1						
Rt	49.9	ohm	1						

Down Device Differential Routing			
L4 length, route as coupled microstrip 100ohm differential trace	2 min to 16 max	inch	1
L4 length, route as coupled stripline 100ohm differential trace	1.8 min to 14.4 max	inch	1

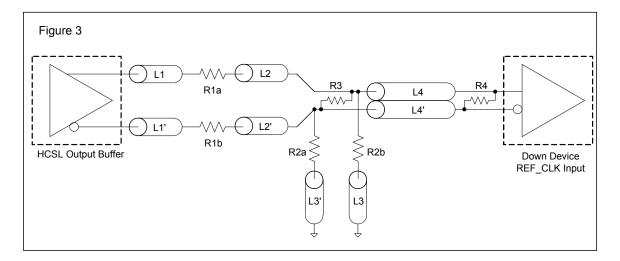
Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace	0.25 to 14 max	inch	2
L4 length, route as coupled stripline 100ohm differential trace	0.225 min to 12.6 max	inch	2



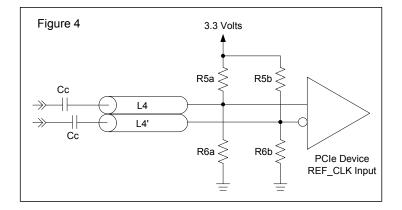


	Alternative Termination for LVDS and other Common Differential Signals (figure 3)									
Vdiff	Vp-р	Vcm	R1	R2	R3	R4	Note			
0.45v	0.22v	1.08	33	150	100	100				
0.58	0.28	0.6	33	78.7	137	100				
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible			
0.60	0.3	1.2	33	174	140	100	Standard LVDS			
R1a = R	1b = R1						•			

R2a = R2b = R2



Cable Connected AC Coupled Application (figure 4)								
Component	Value	Note						
R5a, R5b	8.2K 5%							
R6a, R6b	1K 5%							
Сс	0.1 µF							
Vcm	0.350 volts							



IDT® EIGHT OUTPUT DIFFERENTIAL BUFFER FOR PCIE GEN1, GEN2 AND QPI

General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Co	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
S	lave Address		
WR	WRite		
			ACK
Beg	inning Byte = N		
			ACK
RT	Repeat starT		
S	lave Address		
RD	ReaD		
		_	ACK
		-	Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		e	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
Ν	Not acknowledge		
Р	stoP bit		

	Index BI	ock W	rite Operation
Control	ler (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave	Address		
WR	WRite		
			ACK
Beginnin	g Byte = N		
			ACK
Data Byte	e Count = X		
			ACK
Beginni	ng Byte N		
			ACK
0		×	
0		X Byte	0
0		le	0
			0
Byte N	N + X - 1		
			ACK
Р	stoP bit		

Read Address	Write Address
DD _(H)	DC _(H)

Byt	te 0 Pin #	Name	Control Function	Туре	0	1	Default			
Bit 7	-	PD_Mode	PD# drive mode	RW	driven	Hi-Z	0			
Bit 6	-	STOP_Mode	DIF_Stop# drive mode	RW	driven	Hi-Z	0			
Bit 5	-	PD_Polarity	Select PD polarity	RW	Low	High	0			
Bit 4	-	Reserved	Reserved	RW	Reserved		Х			
Bit 3	-	BYPASS#1	BYPASS#/PLL1	RW	See Bypass Readback Table		Input			
Bit 2	-	PLL_BW#	Select PLL BW	RW	High BW	Low BW	1			
Bit 1	-	BYPASS#0	BYPASS#/PLL0	RW	See Bypass Readback Table		Input			
Bit 0	-	SRC_DIV#	SRC Divide by 2 Select	RW	x/2	x/1	1			

SMBus Table: Frequency Select Register, READ/WRITE ADDRESS (DC/DD)

SMBus Table: Output Control Register

By	te 1	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	42	,41	DIF_7	Output Enable	RW	Disable	Enable	1
Bit 6	38	,37	DIF_6	Output Enable	RW	Disable	Enable	1
Bit 5	34	,33	DIF_5	Output Enable	RW	Disable	Enable	1
Bit 4	30	,29	DIF_4	Output Enable	RW	Disable	Enable	1
Bit 3	20	,21	DIF_3	Output Enable	RW	Disable	Enable	1
Bit 2	16	,17	DIF_2	Output Enable	RW	Disable	Enable	1
Bit 1	12	,13	DIF_1	Output Enable	RW	Disable	Enable	1
Bit 0	8	,9	DIF_0	Output Enable	RW	Disable	Enable	1

NOTE: The SMBus Output Enable Bit must be '1' AND the respective OE pin must be active for the output to run!

SMBus Table: OE Pin Control Register

By	te 2	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	42	,41	DIF_7	DIF_7 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 6	38	,37	DIF_6	DIF_6 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 5	34	,33	DIF_5	DIF_5 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 4	30	,29	DIF_4	DIF_4 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 3	20	,21	DIF_3	DIF_3 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 2	16	,17	DIF_2	DIF_2 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 1	12	,13	DIF_1	DIF_1 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0
Bit 0	8	,9	DIF_0	DIF_0 Stoppable with DIFSTOP	RW	Free-run	Stoppable	0

SMBus Table: Reserved Register

By	te 3	Pin #	Name	Control Function	Туре	0	1	Default	
Bit 7				Reserved				Х	
Bit 6				Reserved					
Bit 5				Reserved					
Bit 4				Reserved					
Bit 3				Reserved					
Bit 2				Reserved				Х	
Bit 1				Reserved				Х	
Bit 0				Reserved					

SMBus Table: Vendor & Revision ID Register

Byte 4	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	RID3		R	-	-	0
Bit 6	-	RID2	REVISION ID	R	-	-	0
Bit 5	-	RID1		R	-	-	0
Bit 4	-	RID0		R	-	-	1
Bit 3	-	VID3		R	-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1	VENDORID	R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBus Table: DEVICE ID

Byte	e 5 Pin	# Name	Control Function	Туре	0	1	Default
Bit 7	-		Device ID 7 (MSB)	RW			1
Bit 6	-		Device ID 6	RW			0
Bit 5	-		Device ID 5	RW			0
Bit 4	-		Device ID 4		Device ID is 82 Hex		0
Bit 3	-		Device ID 3		for 9DB823		0
Bit 2	-		Device ID 2		1		0
Bit 1	-		Device ID 1	RW			1
Bit 0	-		Device ID 0	RW			0

SMBus Table: Byte Count Register

Byt	Byte 6 Pin # Name		Name	Control Function		0	1	Default
Bit 7	-		BC7		RW	-	-	0
Bit 6	-		BC6		RW	-	-	0
Bit 5	-		BC5		RW	-	-	0
Bit 4	-		BC4	Writing to this register configures how many bytes will be read back.	RW	-	-	0
Bit 3	-		BC3		RW	-	-	0
Bit 2	-		BC2		RW	-	-	1
Bit 1	-		BC1		RW	-	-	1
Bit 0	-		BC0		RW	-	-	1

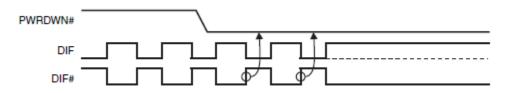
Note: Polarities in timing diagrams are shown OE_INV = 0. They are similar to OE_INV = 1.

PD#, Power Down

The PD# pin cleanly shuts off all clocks and places the device into a power saving mode. PD# must be asserted before shutting off the input clock or power to insure an orderly shutdown. PD is asynchronous active-low input for both powering down the device and powering up the device. When PD# is asserted, all clocks will be driven high, or tri-stated (depending on the PD# drive mode and Output control bits) before the PLL is shut down.

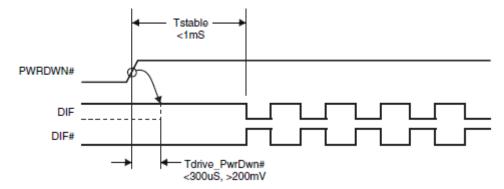
PD# Assertion

When PD# is sampled low by two consecutive rising edges of DIF#, all DIF outputs must be held High, or tri-stated (depending on the PD# drive mode and Output control bits) on the next High-Low transition of the DIF# outputs. When the PD# drive mode bit is set to '0', all clock outputs will be held with DIF driven High with 2 x IREF and DIF# tri-stated. If the PD# drive mode bit is set to '1', both DIF and DIF# are tri-stated.



PD# De-assertion

Power-up latency is less than 1 ms. This is the time from de-assertion of the PD# pin, or VDD reaching 3.3V, or the time from valid SRC_IN clocks until the time that stable clocks are output from the device (PLL Locked). If the PD# drive mode bit is set to '1', all the DIF outputs must driven to a voltage of >200 mV within 300 us of PD# de-assertion.



DIF_STOP#

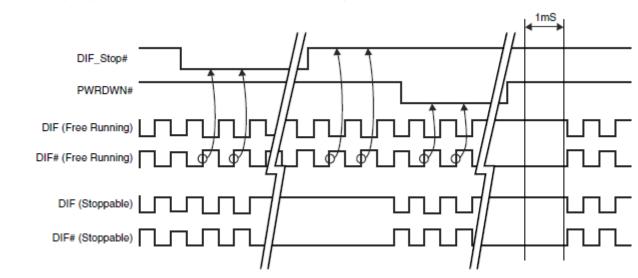
The DIF_STOP# signal is an active-low asynchronous input that cleanly stops and starts the DIF outputs. A valid clock must be present on SRC_IN for this input to work properly. The DIF_STOP# signal is de-bounced and must remain stable for two consecutive rising edges of DIF# to be recognized as a valid assertion or de-assertion.

DIF_STOP# - Assertion

Asserting DIF_STOP# causes all DIF outputs to stop after their next transition (if the control register settings allow the output to stop). When the DIF_STOP# drive bit is '0', the final state of all stopped DIF outputs is DIF = High and DIF# = Low. There is no change in output drive current. DIF is driven with 6xIREF. DIF# is not driven, but pulled low by the termination. When the DIF_STOP# drive bit is '1', the final state of all DIF output pins is Low. Both DIF and DIF# are not driven.

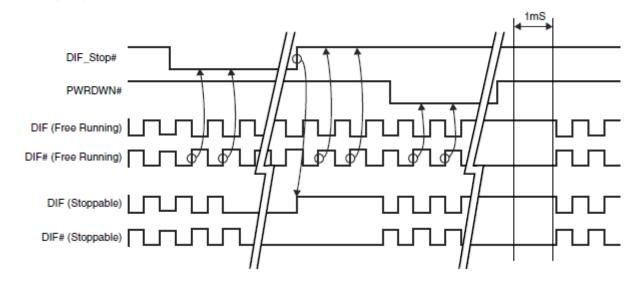
DIF_STOP# - De-assertion (transition from '0' to '1')

All stopped differential outputs resume normal operation in a glitch-free manner. The de-assertion latency to active outputs is 2-6 DIF clock periods, with all DIF outputs resuming simultaneously. If the DIF_STOP# drive control bit is '1' (tri-state), all stopped DIF outputs must be driven High (>200 mV) within 10 ns of de-assertion.

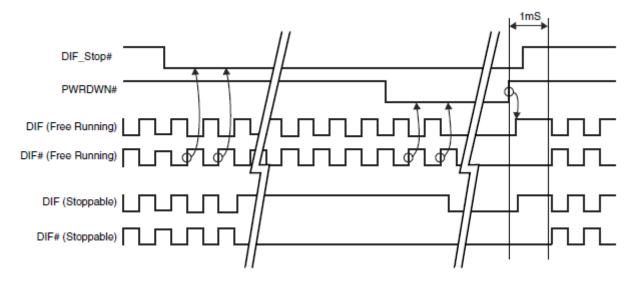


DIF_STOP_1 (Stop_Mode = Driven, PD_Mode = Driven)

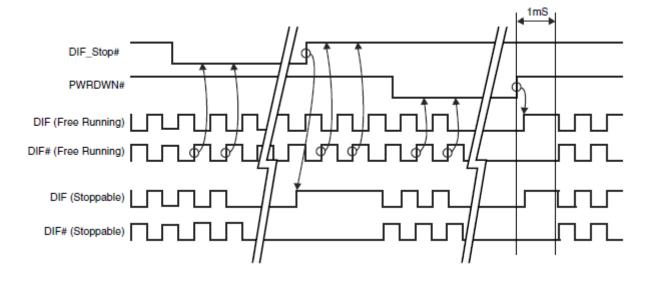
DIF_STOP_2 (Stop_Mode = Tristate, PD_Mode = Driven)



DIF_STOP_3 (Stop_Mode = Driven, PD_Mode = Tristate)

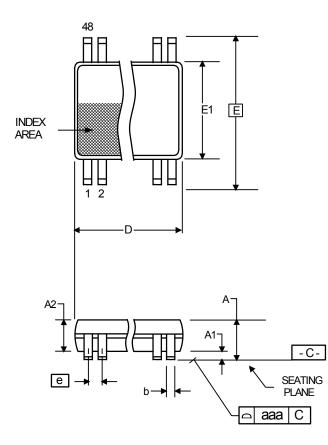


DIF_STOP_4 (Stop_Mode = Tristate, PD_Mode = Tristate)



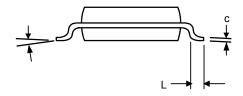
Package Outline and Package Dimensions (48-pin TSSOP, 6.10mm Body, 0.50 Pitch)

Package dimensions are kept current with JEDEC Publication No. 95



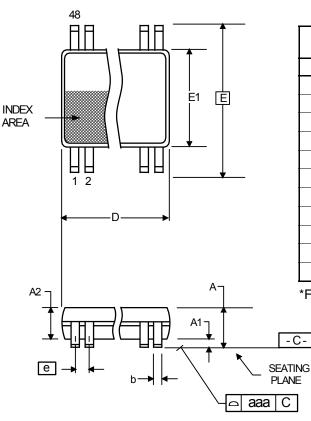
	Millim	neters	Incl	nes*
Symbol	Min	Max	Min	Max
A		1.20		0.047
A1	0.05	0.15	0.002	0.006
A2	0.80	1.05	0.032	0.041
b	0.17	0.27	0.007	0.011
С	0.09	0.20	0.0035	0.008
D	12.40	12.60	0.488	0.496
E	8.10 BASIC		0.319 BASIC	
E1	6.00	6.20	0.236	0.244
е	0.50 Basic		0.020 Basic	
L	0.45	0.75	0.018	0.030
α	0 °	8 °	0 °	8 °
aaa		0.10		0.004

*For reference only. Controlling dimensions in mm.



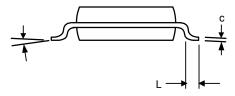
Package Outline and Package Dimensions (48-pin SSOP, 300 mil)

Package dimensions are kept current with JEDEC Publication No. 95



	Millin	neters	Inch	nes*
Symbol	Min Max		Min	Max
A	2.41	2.80	.095	.110
A1	0.20	0.40	.008	.016
b	0.20	0.34	.008	.0135
С	0.13	0.25	.005	.010
D	15.75	16.00	.620	.630
E	10.03	10.68	.395	.420
E1	7.40	7.60	.291	.299
е	0.635	BASIC	0.025 BASIC	
h	0.38	0.64	.015	.025
L	0.50	1.02	.020	.040
α	0°	8 °	0 °	8°

*For reference only. Controlling dimensions in mm.



Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DB823BFLF	Tubes	48-pin SSOP	0 to +70°C
9DB823BFLFT	Tape and Reel	48-pin SSOP	0 to +70°C
9DB823BGLF	Tubes	48-pin TSSOP	0 to +70°C
9DB823BGLFT	Tape and Reel	48-pin TSSOP	0 to +70°C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

"B" is the device revision designator (will not correlate with the datasheet revision).

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Revision History

Rev.	Issue Date	Description	Page #
		 Updated Electrical Characteristics to add propagation delay and phase noise information. Added SMBus electrical characteristics Added foot note about DIF input running in order for the SMBus interface to work Added foot note to Byte 1 about functionality of OE bits and OE pins Updated clock periods to reflect +/-100ppm input clock tolerance (CK410B+/CK420BQ/CK505). Changed SRC_Stop references to DIF_Stop references for 	
А	10/1/2008	consistency	Various
В	10/7/2008	Corrected Common Dimensions.	19-20
С	2/4/2010	1. Corrected Polarity of Power Down pin when OE_INV = 1. Power Down is always active low (or PD#). This is a difference from the 9DB803D.	Various
0	2/4/2010	1. Corrected Termination drawings/tables	vanous
D	8/31/2010	2. Removed "Polarity Inversion Pin List" table.	Various
F	5/9/2011	1. Update pin 2 pin-name and pin description from VDD to VDDR. This highlights that optimal peformance is obtained by treating VDDR as in	Various
	5/9/2011	analog pin. This is a document update only, there is no silicon change. Updated Byte 2, bits 0~7 per char review. Outputs can be programmed	vanous
F	9/18/2012	with Byte 2 to be Stoppable or Free-Run with DIF_Stop pin, not the OE pins.	14

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